

# Cree® EZ400™ Gen II LED

## Data Sheet

### CxxxEZ400-Sxxx00-2

Cree's EZBright™ LEDs are the next generation of solid-state LED emitters that combine highly efficient InGaN materials with Cree's proprietary optical design and device technology to deliver superior value for high-intensity LEDs. The optical design maximizes light extraction efficiency and enables a Lambertian radiation pattern. Additionally, these LEDs are die attachable with conductive epoxy, solder paste or solder preforms, as well as the flux eutectic method. These vertically structured, low forward voltage LED chips are approximately 170 microns in height. Cree's EZ™ chips are tested for conformity to optical and electrical specifications. These LEDs are useful in a broad range of applications, such as general illumination, automotive lighting and LCD backlighting.

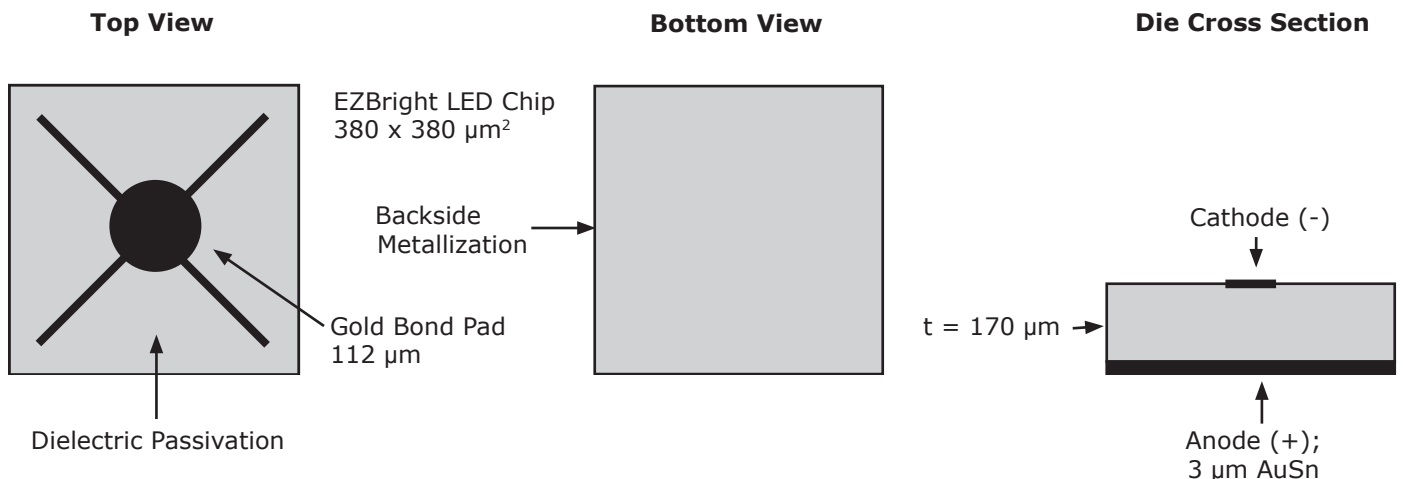
#### FEATURES

- EZBright Power Chip LED Rf Performance
  - 90 mW min. @ 150 mA - 450 & 460 nm
  - 75 mW min. @ 150 mA - 470 nm
  - 25 mW min. @ 150 mA - 527 nm
- Lambertian Radiation
- Conductive Epoxy, Solder Paste or Preforms, or Flux Eutectic Attach
- Low Forward Voltage - 3.5 V Typical at 150 mA
- Single Wire Bond Structure
- Maximum DC Forward Current - 200 mA
- Dielectric Passivation Across Epi Surface

#### APPLICATIONS

- General Illumination
  - Automobile
  - Aircraft
  - Decorative Lighting
  - Task Lighting
  - Outdoor Illumination
- White LEDs
- Crosswalk Signals
- Television Backlighting

#### CxxxEZ400-Sxxx00 Chip Diagram



Maximum Ratings at $T_A = 25^\circ\text{C}$ <sup>Note 1</sup>		CxxxEZ400-Sxxx00-2
DC Forward Current		200 mA
Peak Forward Current		350 mA <sup>Note 3</sup>
LED Junction Temperature		145°C
Reverse Voltage		5 V
Operating Temperature Range		-40°C to +100°C
Storage Temperature Range		-40°C to +120°C

Typical Electrical/Optical Characteristics at $T_A = 25^\circ\text{C}$ , $I_f = 150\text{ mA}$ <sup>Note 2</sup>					
Part Number	Forward Voltage ( $V_F$ , V)			Reverse Current [ $I(V_R=5\text{ V})$ , $\mu\text{A}$ ]	Full Width Half Max ( $\lambda_D$ , nm)
	Min.	Typ.	Max.	Max.	Typ.
C450EZ400-Sxxx00-2	3.1	3.5	4.1	2	20
C460EZ400-Sxxx00-2	3.1	3.5	4.1	2	21
C470EZ400-Sxxx00-2	3.1	3.5	4.1	2	24
C527EZ400-Sxxx00-2	3.2	3.7	4.2	2	35

Mechanical Specifications			CxxxEZ400-Sxxx00-2
Description	Dimension	Tolerance	
P-N Junction Area ( $\mu\text{m}$ )	350 x 350	$\pm 40$	
Chip Area ( $\mu\text{m}$ )	380 x 380	$\pm 40$	
Chip Thickness ( $\mu\text{m}$ )	170	$\pm 25$	
Top Au Bond Pad Diameter ( $\mu\text{m}$ )	112	$\pm 15$	
Au Bond Pad Thickness ( $\mu\text{m}$ )	3.0	$\pm 1.0$	
Back Contact Metal Area ( $\mu\text{m}$ )	380 x 380	$\pm 40$	
Back Contact Metal Thickness ( $\mu\text{m}$ )	3.0	$\pm 1.0$	

#### Notes:

- Maximum ratings are package-dependent. The above ratings were determined using a Au-plated TO39 header without an encapsulant for characterization. Ratings for other packages may differ. The junction temperature should be characterized in a specific package to determine limitations. Assembly processing temperature must not exceed 325°C (< 5 seconds). See Cree EZBright Applications Note for assembly-process information.
- All products conform to the listed minimum and maximum specifications for electrical and optical characteristics when assembled and operated at 150 mA within the maximum ratings shown above. Efficiency decreases at higher currents. Typical values given are within the range of average expected by the manufacturer in large quantities and are provided for information only. All measurements were made using a Au-plated TO39 header without an encapsulant. Optical characteristics measured in an integrating sphere using Illuminance E.
- This peak forward current specification is based on a 400-ms pulse width at a 1/5-duty cycle with a junction temperature of 65°C.

## Standard Bins for CxxxEZ400-Sxxx00-2

LED chips are sorted to the **radiant flux** and **dominant wavelength** bins shown. A sorted die sheet contains die from only one bin. Sorted die kit (CxxxEZ400-Sxxx00-2) orders may be filled with any or all bins (CxxxEZ400-0xxx-2) contained in the kit. All radiant flux and all dominant wavelength values shown and specified are at  $I_f = 150$  mA. Radiant flux values are measured using Au-plated TO39 headers without an encapsulant.

### C450EZ400-S09000-2

Radiant Flux	120 mW	C450EZ400-0213-2	C450EZ400-0214-2	C450EZ400-0215-2	C450EZ400-0216-2	
	105 mW	C450EZ400-0209-2	C450EZ400-0210-2	C450EZ400-0211-2	C450EZ400-0212-2	
	90 mW	C450EZ400-0205-2	C450EZ400-0206-2	C450EZ400-0207-2	C450EZ400-0208-2	
		445 nm	447.5 nm	450 nm	452.5 nm	455 nm
		<b>Dominant Wavelength</b>				

### C460EZ400-S09000-2

Radiant Flux	120 mW	C460EZ400-0213-2	C460EZ400-0214-2	C460EZ400-0215-2	C460EZ400-0216-2	
	105 mW	C460EZ400-0209-2	C460EZ400-0210-2	C460EZ400-0211-2	C460EZ400-0212-2	
	90 mW	C460EZ400-0205-2	C460EZ400-0206-2	C460EZ400-0207-2	C460EZ400-0208-2	
		455 nm	457.5 nm	460 nm	462.5 nm	465 nm
		<b>Dominant Wavelength</b>				

### C470EZ400-S07500-2

Radiant Flux	105 mW	C470EZ400-0209-2	C470EZ400-0210-2	C470EZ400-0211-2	C470EZ400-0212-2	
	90 mW	C470EZ400-0205-2	C470EZ400-0206-2	C470EZ400-0207-2	C470EZ400-0208-2	
	75 mW	C470EZ400-0201-2	C470EZ400-0202-2	C470EZ400-0203-2	C470EZ400-0204-2	
		465 nm	467.5 nm	470 nm	472.5 nm	475 nm
		<b>Dominant Wavelength</b>				

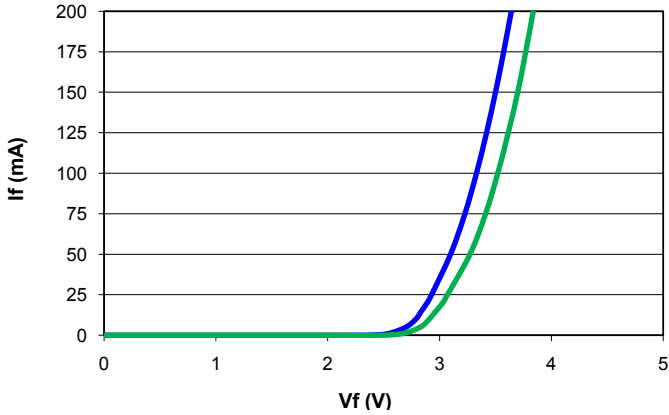
### C527EZ400-S2500-2

Radiant Flux	50 mW	C527EZ400-0207-2	C527EZ400-0208-2	C527EZ400-0209-2	
	40 mW	C527EZ400-0204-2	C527EZ400-0205-2	C527EZ400-0206-2	
	25 mW	C527EZ400-0201-2	C527EZ400-0202-2	C527EZ400-0203-2	
		520 nm	525 nm	530 nm	535 nm
		<b>Dominant Wavelength</b>			

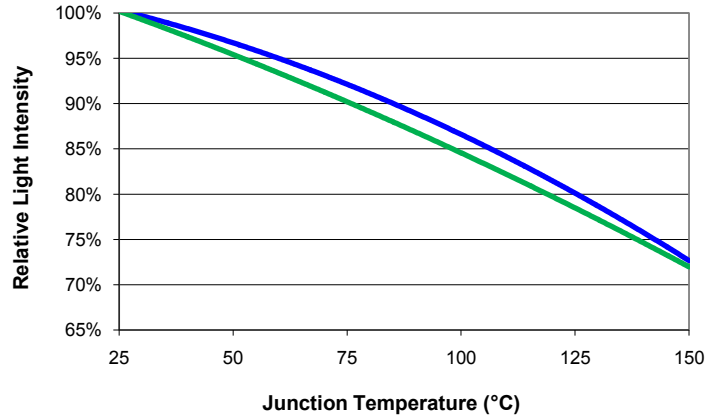
# Characteristic Curves

These are representative measurements for the EZBright400. Actual curves will vary slightly for the various radiant flux and dominant wavelength bins.

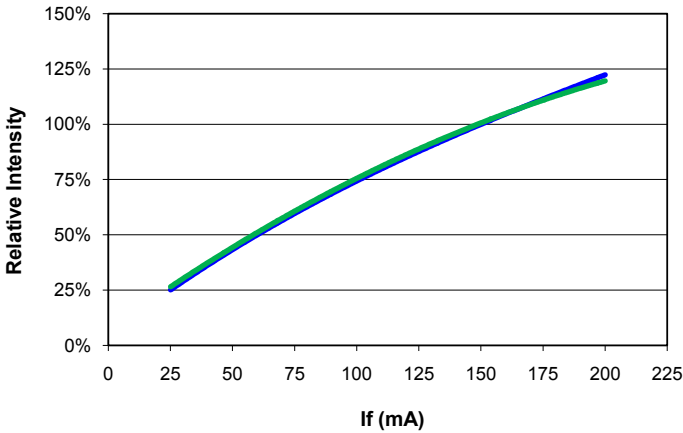
**Forward Current vs. Forward Voltage**



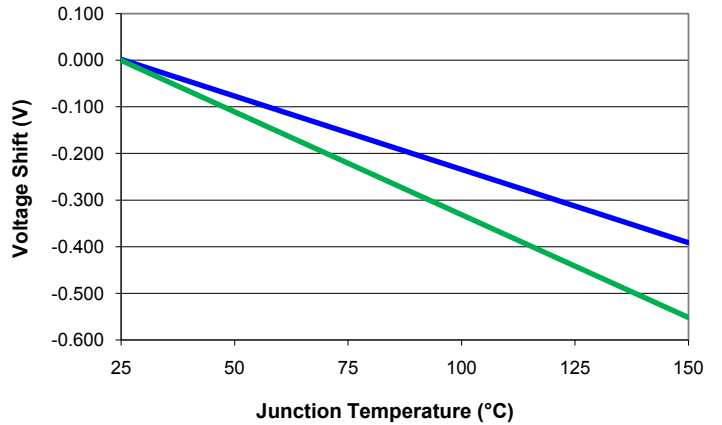
**Relative Light Intensity vs Junction Temperature**



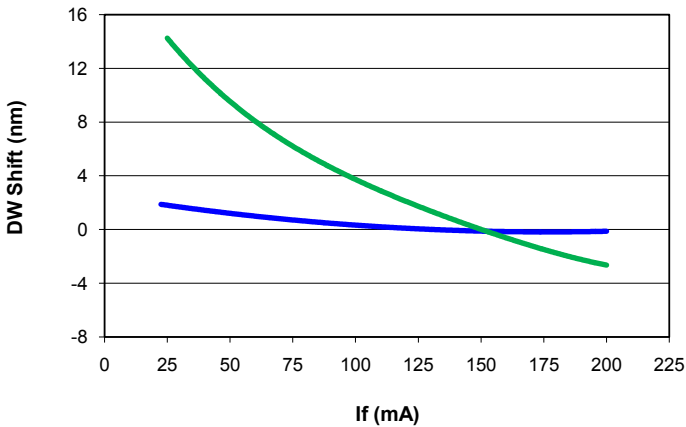
**Relative Intensity vs. Forward Current**



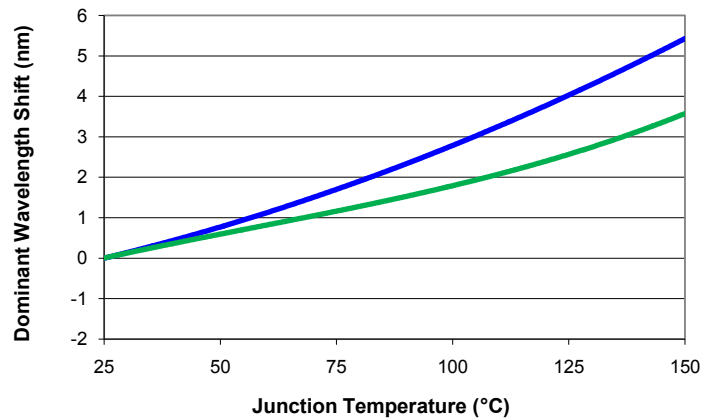
**Voltage Shift vs Junction Temperature**



**Wavelength Shift vs. Forward Current**



**Dominant Wavelength Shift vs Junction Temperature**



## Radiation Pattern

This is a representative radiation pattern for the EZBright Power Chip LED product. Actual patterns will vary slightly for each chip.

